



## Galvanic isolated octal high-side power solid state relay for high inductive loads





PowerSO-36

TFQFPN32

## **Features**

- V<sub>CC(AMR)</sub> = 45 V
- Wide process side op. range V<sub>CC</sub> = 9.2 to 36 V
- $R_{DS}(on) = 0.125 \Omega \text{ per channel (TYP)}$
- Fast demagnetization of inductive loads V<sub>DEMAG(TYP)</sub> = V<sub>CC</sub> 54 V
- Per channel process side op. current
  - ISO808/ISO808Q I<sub>OUT</sub> < 0.7 A</li>
  - ISO808-1/ISO808Q-1 I<sub>OUT</sub> < 1 A</li>
- Low process and logic sides supply current
- Under-voltage shut down with auto restart and hysteresis
- Logic side 5 V and 3.3 V TTL/CMOS and MCU compatible I/Os
- Common output enable/disable pin
- · Reset function for IC outputs disable
- High common mode transient immunity
- Short circuit protection on output channels
  - ISO808/ISO808Q I<sub>LIM(MIN)</sub> = 0.7 A
    - ISO808-1/ISO808Q-1 I<sub>LIM(MIN)</sub> = 1 A
- Per-channel over-temperature protection with thermal independence of separate channels
- Case over-temperature protection
- Over-voltage protection (V<sub>CC</sub> clamping)
- Loss of GND and V<sub>CC</sub> protections
- Common fault open drain diagnostic
- Designed to meet IEC 61000-4-2, IEC 61000- 4-4, IEC 61000-4-5 and IEC 61000-4-8
- UL1577 and UL508 certified
- PowerSO-36 and TFQFPN32 Package

## **Applications**

- Programmable logic control
- Industrial PC peripheral input/output
- · Numerical control machines
- Drivers for all type of loads (resistive, capacitive, inductive)







## **Description**

The ISO808, ISO808-1 (PowerSO-36) and ISO808Q, ISO808Q-1 (TFQFPN32) are galvanic isolated 8-channel drivers featuring a low supply current. Each driver contains 2 independent galvanic isolated voltage domains ( $V_{CC}$  and  $V_{DD}$  for the Process and Control Logic stages, respectively). The ICs are intended for driving any kind of load with one side connected to ground.

Active channel current limitation (OVL) combined with thermal shutdown (OVT), independent for each channel, protects the device against overload.

Built-in thermal shutdown protects each channel from overtemperature and overload: each overheated channel automatically turns OFF after its junction temperature triggers the protection threshold ( $T_{JSD}$ ). The channel turns back ON if its junction temperature decreases lower than restart threshold ( $T_{JR}$ ).

An additional case temperature sensor protects the whole chip against overtemperature (OVC event): if the case temperature triggers the  $T_{CSD}$  threshold then overloaded channels are turned OFF and restart only when case temperature decreased down to the reset threshold ( $T_{CR}$ ). Non overloaded channels continue to operate normally.

Other embedded functions are loss of ground protection, V<sub>CC</sub> and V<sub>DD</sub> UVLOs (with hysteresis), and watchdog.

An internal circuit provides an OR-wired not latched OVT that is reported on the common FAULT indicator pin. FAULT is an open drain, active low, fault indication pin.

The Synchronous Control Mode (by driving  $\overline{\text{SYNC}}$  and  $\overline{\text{LOAD}}$  pins independently) is used to reduce the jittering of the outputs and to drive at the same time the outputs of different devices.

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# 1 Block diagram

 $\mathsf{GND}_\mathsf{DD}$ 

VDD vcc UVLO<sub>cc</sub> UVLOcc <u>SYNC</u>  $\overline{LOAD}$ FAST DEMAG IN1 THERMAL JUNCTION Galvanic Isolation CONTROL CONTROL CURRENT LOGIC LIMITATION LOGIC OUT1 IN8 OUT\_EN OUT8 THERMAL CASE **FAULT** 

 $\text{GND}_{\text{CC}}$ 

Figure 1. Block diagram

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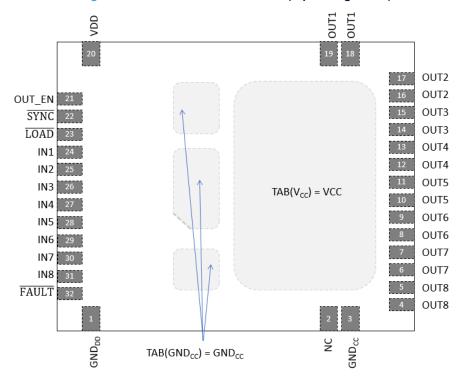


## 2 Pin connection

36 OUT1 NC 1 VDD 2 <sup>35</sup> OUT1 OUT\_EN 3 34 OUT2 SYNC 4 33 OUT2 LOAD 5 32 OUT3 IN1 6 31 OUT3 IN2 7 30 OUT4 IN3 8 <sup>29</sup> OUT4 IN4 9 <sup>28</sup> OUT5 TAB = VCCIN5 10 27 OUT5 IN6 11 26 OUT6 IN7 12 25 OUT6 IN8 13 24 OUT7 FAULT 14 23 OUT7 GND<sub>DD</sub> 15 22 OUT8 21 OUT8 NC 16 NC 17 20 NC NC 18 19 GND<sub>cc</sub>

Figure 2. Pin connection PowerSO-36 (top through view)





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Table 1. Pin description

Pin					
PowerSO-36	TFQFPN32	Name	Description		
1	-	N.C.	Not connected		
2	20	V <sub>DD</sub>	Positive Control Logic Stage supply		
3	21	OUT_EN	Output enable		
4	22	SYNC	Input to output synchronization signal, active low		
5	23	LOAD	Load input data signal, active low		
6	24	IN1	Channel 1 input		
7	25	IN2	Channel 2 input		
8	26	IN3	Channel 3 input		
9	27	IN4	Channel 4 input		
10	28	IN5	Channel 5 input		
11	29	IN6	Channel 6 input		
12	30	IN7	Channel 7 input		
13	31	IN8	Channel 8 input		
14	32	FAULT	Common fault (OVT and Internal Communication Error) diagnostic pin - active low		
15	1	GND <sub>DD</sub>	Input logic ground, negative logic supply		
16	-	NC	Not connected		
17	-	NC	Not connected		
18	2	NC	Not connected		
19	3, TAB(GND <sub>CC</sub> )	GND <sub>CC</sub>	Output power ground		
20	-	NC	Not connected		
21	4				
22	5	OUT8	Channel 8 power output <sup>(1)</sup>		
23	6				
24	7	OUT7	Channel 7 power output <sup>(1)</sup>		
25	8	01170			
26	9	OUT6	Channel 6 power output <sup>(1)</sup>		
27	10	OUTE	01 15 (11)		
28	11	OUT5	Channel 5 power output <sup>(1)</sup>		
29	12	OUT4	01		
30	13	OUT4	Channel 4 power output <sup>(1)</sup>		
31	14	OUT2	Oh 1.0		
32	15	OUT3	Channel 3 power output <sup>(1)</sup>		
33	16	OUTO	Channel 2 newer output(1)		
34	17	OUT2	Channel 2 power output <sup>(1)</sup>		
35	18	OUT4	Channel 1 newer output(1)		
36	19	OUT1	Channel 1 power output <sup>(1)</sup>		
TAB	TAB(V <sub>CC</sub> )	V <sub>CC</sub>	Exposed tab internally connected to V <sub>CC</sub> positive Process Stage supply voltage		

<sup>1.</sup> Connect the two pins on the same net of the application board

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# Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Min.	Max.	Unit
V <sub>CC</sub>	Process Stage supply voltage	-0.3	+45	V
$V_{DD}$	Control Logic Stage supply voltage	-0.3	+6	V
V <sub>IN</sub>	DC Input pins (IN <sub>X</sub> , <del>LOAD</del> , <del>SYNC</del> and OUT_EN) voltage	-0.3	$V_{DD}$	V
V <sub>FAULT</sub>	FAULT pin voltage	-0.3	+6.0	V
$I_{GNDdd}$	DC digital ground Reverse Current		-25	mA
I <sub>OUT</sub>	Channel Output Current (continuous)		Internally limited	Α
I <sub>GNDcc</sub>	DC Power Ground Reverse Current		-250	mA
I <sub>RX</sub>	Reverse Output Current (from OUTx pins to V <sub>CC</sub> )		-6 <sup>(1)</sup>	Α
I <sub>IN</sub>	DC Input pins (IN <sub>X</sub> , <del>LOAD</del> , <del>SYNC</del> and OUT_EN) voltage	-10	+10	mA
I <sub>FAULT</sub>	FAULT pin current	-10	+10	mA
V <sub>ESD</sub>	Electrostatic discharge with Human Body Model (R = 1.5 KΩ; C = 100 pF)		2000	V
V	Isolation DC voltage applied between GND <sub>DD</sub> and GND <sub>CC</sub> pins for PowerSO-36		180	V
V <sub>IO</sub>	Isolation DC voltage applied between GND <sub>DD</sub> and GND <sub>CC</sub> pins for TFQFPN32		75	V
EAS	Single pulse avalanche energy per channel, all channels driven simultaneously $@T_{AMB}$ = 125 °C, $I_{OUT}$ = 0.6 A (PowerSO-36)		2.11	J
EAS	Single pulse avalanche energy per channel, all channels driven simultaneously $@T_{AMB}$ = 125 °C, $I_{OUT}$ = 0.6 A (TFQFPN32)		0.48	J
P <sub>TOT</sub>	Power dissipation		Internally limited (2)	W
TJ	Junction operating temperature		Internally limited(2)	°C
T <sub>STG</sub>	Storage temperature		-40 to 150	°C

<sup>1.</sup> this value is intended with each couple of OUTx pins shorted on the application board

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<sup>2.</sup> Protection functions are intended to avoid IC damage in fault conditions and are not intended for continuous operation. Continuous or repetitive operation of protection functions may reduce the IC lifetime.



# 4 Thermal data

Table 3. Thermal data

Symbol	Parameter	Max. v	alue	Unit
Symbol	raidilletei	PowerSO-36	TFQFPN32	Onne
R <sub>th j-case</sub>	Thermal resistance, junction-to-case (1)	0.8	1	°C/W
R <sub>th j- amb</sub>	Thermal resistance, junction-to-ambient (2)			C/VV

<sup>1.</sup> Rth between the die and the bottom case surface measured by cold plate as per JESD51-12.

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<sup>2.</sup> JESD51-7.



## 5 Electrical characteristics

9.2 V  $\leq$  V<sub>CC</sub>  $\leq$  36 V; 2.75 V  $\leq$  V<sub>DD</sub>  $\leq$  5.5 V; -40 °C < T<sub>J</sub> < 125 °C, unless otherwise specified.

**Table 4. Power section** 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$V_{CC}$	Operating voltage range		9.2		36	V
V <sub>CC(THON)</sub>	V <sub>CC</sub> undervoltage turn-on threshold	V <sub>DD</sub> = 3.3 V, V <sub>CC</sub> increasing		8.4	9.2	V
V <sub>CC(THOFF)</sub>	V <sub>CC</sub> undervoltage turn-off threshold	V <sub>DD</sub> = 3.3 V, V <sub>CC</sub> decreasing	7.7	8.1		V
V <sub>CC(HYS)</sub>	V <sub>CC</sub> undervoltage hysteresis			0.15		V
V <sub>CCclamp</sub>	Clamp on VCC pin	I <sub>clamp</sub> = 20 mA	47	52	57	V
	ON-state resistance (see Figure 4)	I <sub>OUT</sub> = 0.5 A, T <sub>J</sub> = 25 °C		0.125	0.16	
R <sub>DS(ON)</sub>		I <sub>OUT</sub> = 0.5 A, T <sub>J</sub> = 125 °C			0.26	Ω
	Development .	All channels in OFF-state, V <sub>CC</sub> = 36 V		5.5		^
Icc	Power supply current	All channels in ON-state, $V_{CC}$ = 36 V		16		mA
I <sub>LGND</sub>	Ground disconnection output current	V <sub>CC</sub> = V <sub>GND</sub> = 0 V, V <sub>OUT</sub> = -24 V			500	μA
V <sub>OUT(OFF)</sub>	OFF-state output voltage	Channel OFF and I <sub>OUT</sub> = 0 A			3	V
I <sub>OUT(OFF)</sub>	OFF-state output current	Channel OFF and V <sub>OUT</sub> = 0 V			5	μA

Table 5. Digital supply voltage

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$V_{DD}$	Operating voltage range		2.75		5.5	V
V <sub>DD(THON)</sub>	V <sub>DD</sub> undervoltage turn-on threshold	V <sub>CC</sub> = 24 V, V <sub>DD</sub> increasing	2.55		2.75	V
V <sub>DD(THOFF)</sub>	V <sub>DD</sub> undervoltage turn-off threshold	V <sub>CC</sub> = 24V, V <sub>DD</sub> decreasing	2.45		2.65	V
V <sub>DD(HYS)</sub>	V <sub>DD</sub> undervoltage hysteresis		0.04	0.1		V
las	V <sub>DD</sub> supply current	V <sub>DD</sub> = 5 V and input channel with a steady logic level		4.5	6	mA
I <sub>DD</sub>	VDD suppry current	$V_{DD}$ = 3.3 V and input channel with a steady logic level		4.4	5.9	mA

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Table 6. Diagnostic pin and output protection function

Symbol	Parame	eter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>FAULT</sub>	FAULT pin open drain voltag	e output low	I <sub>FAULT</sub> = 5 mA			0.4	V
I <sub>LFAULT</sub>	FAULT output leakage currer	AULT output leakage current				1	μA
I <sub>PEAK</sub>	Maximum DC output current before limitation					2.3	Α
I <sub>LIM</sub>	Short-circuit current	ISO808, ISO808Q	V = 24 V: B = 0.0	0.7		1.9	_
	limitation ISO80	ISO808-1, ISO808Q-1	$V_{CC} = 24 \text{ V}; R_{LOAD} = 0 \Omega$	1			Α
Hyst	I <sub>LIM</sub> tracking limits	LIM tracking limits			0.3		Α
T <sub>JSD</sub>	Junction shutdown temperate	ure		150	175	200	°C
T <sub>JR</sub>	Junction reset temperature				150		°C
T <sub>JHYST</sub>	Junction thermal hysteresis				15		°C
T <sub>CSD</sub>	Case shutdown temperature			125	130	135	°C
T <sub>CR</sub>	Case reset temperature				115		°C
T <sub>CHYST</sub>	Case thermal hysteresis				15		°C
V <sub>DEMAG</sub>	Output voltage at turn-off		I <sub>OUT</sub> = 0.5 A; I <sub>LOAD</sub> >= 1 mH	V <sub>CC</sub> -50	V <sub>CC</sub> -54	V <sub>CC</sub> -58	V

Table 7. Power switching characteristics (V<sub>CC</sub> = 24 V; R<sub>LOAD</sub> = 48  $\Omega$ ; -40 °C < T<sub>J</sub> < 125 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
dV/dt(ON)	Turn-on voltage slope			0.7		V/µs
tr	Rise time	(aga Figura F.)		19	32	μs
dV/dt(OFF)	Turn-off voltage slope	(see Figure 5 )		1.5		V/µs
tf	Fall time			7	23	μs
td(ON)	Turn-ON delay time	(see Figure 6, Figure 7)		15	24	μs
td(OFF)	Turn-OFF delay time	(See Figure 6, Figure 7)		43	80	μs
t <sub>w(OUT_EN)</sub>	OUT_EN pulse width	(see Figure 9, Figure 10)	150			ns
t <sub>p(OUT_EN)</sub>	OUT_EN propagation delay			40	80	μs

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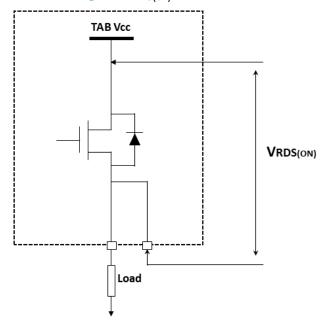
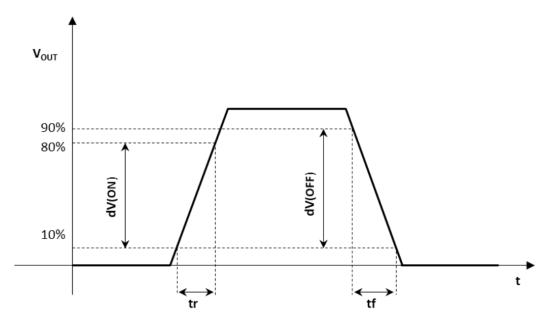


Figure 4. R<sub>DS(on)</sub> measurement





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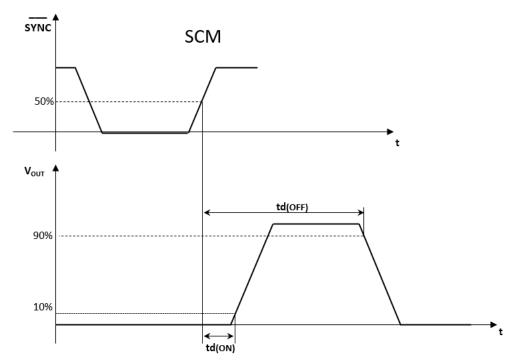
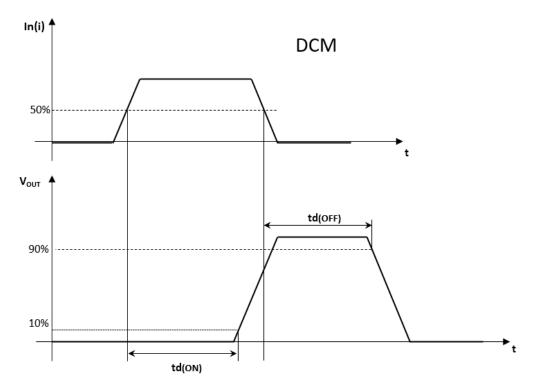


Figure 6. td(ON)-td(OFF) Synchronous Control Mode (SCM)





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### Table 8. Logic inputs and output

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>IL</sub>	TOAD, SYNC, IN <sub>X</sub> and OUT_EN low level voltage		-0.3		0.3 x V <sub>DD</sub>	V
V <sub>IH</sub>	$\overline{\text{LOAD}}$ , $\overline{\text{SYNC}}$ , $\text{IN}_{X}$ and $\text{OUT\_EN}$ high level voltage		0.7 x V <sub>DD</sub>		V <sub>DD</sub> +0.3	V
V <sub>I(HYST)</sub>	$\overline{\text{LOAD}}$ , $\overline{\text{SYNC}}$ , $\text{IN}_{\text{X}}$ and $\text{OUT\_EN}$ hysteresis voltage	V <sub>DD</sub> = 5 V		100		mV
I <sub>IN</sub>	LOAD, SYNC, IN <sub>X</sub> and OUT_EN current	V <sub>IN</sub> = 5 V	10	55	90	μA

Table 9. Parallel interface timings ( $V_{DD}$  = 5 V;  $V_{CC}$  = 24 V; -40 °C < T<sub>J</sub> < 125 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>dis(SYNC)</sub>	SYNC disable time	Sync. control mode	10			μs
t <sub>dis(DCM)</sub>	SYNC, LOAD disable time	Direct control mode	80			ns
t <sub>w(SYNC)</sub>	SYNC negative pulse width	Sync. control mode	20		195	μs
t <sub>su(LOAD)</sub>	LOAD setup time	Sync. control mode	80			ns
t <sub>h(LOAD)</sub>	LOAD hold time	Sync. control mode	400			ns
t <sub>w(LOAD)</sub>	LOAD pulse width	Sync. control mode	240			ns
t <sub>su(IN)</sub>	Input setup time		80			ns
t <sub>h(IN)</sub>	Input hold time		10			ns
•	Input pulse width	Sync. control mode	160			ns
t <sub>w(IN)</sub>	Input pulse width	Direct control mode	20			μs
t <sub>INLD</sub>	IN to LOAD time	Direct control mode from IN variation to LOAD falling edge	80			ns
t <sub>LDIN</sub>	LOAD to IN time	Direct control mode from $\overline{\text{LOAD}}$ falling edge to IN variation	400			ns
t <sub>jitter(SCM)</sub>		Sync. control mode			6	
t <sub>jitter(DCM)</sub>	Jitter on single channel	Direct control mode			20	μs

Table 10. Internal communication timings (V<sub>DD</sub> = 5 V; V<sub>CC</sub> = 24 V; -40 °C <  $T_J$  < 125 °C)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
f <sub>refresh</sub>	Refresh delay			15		kHz
t <sub>WD</sub>	Watchdog time		272	320	400	μs

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Table 11. Insulation a	and safety-related	specifications

Symbol	Parameter	Test conditions	Val	Unit	
	Parameter	rest conditions	PowerSO 36	TFQFPN32	Unit
CLR <sup>(1)</sup>	Clearance (minimum external air gap)	Measured from input terminals to output terminals, shortest distance through air	2.6	3.3	mm
CPG (1)	Creepage (minimum external tracking)	Measured from input terminals to output terminals, shortest distance path along body	2.6	3.3	mm
CTI <sup>(2)</sup>	Comparative tracking index (tracking resistance)		≥400	≥600	V
OTE	Isolation group	Material group	II	I	-

- Creepage and clearance requirements should be applied according to the specific equipment isolation standard of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the PCB do not reduce this distance.
- 2. When high voltage is applied across the isolator, electric discharges on or close to the surface of the package, can cause localized deterioration in the mold compound, resulting in a partially conducting path from one side of the isolator to the other. This phenomenon is called tracking. The ability of a material to withstand tracking is quantified by a comparative tracking index (CTI). Using a mold compound with a higher CTI allows the use of smaller packages and saves board space.

**Table 12. Insulation characteristics** 

Symbol	Parameter	Test condition	Value		Unit		
	Parameter	rest condition	PowerSO 36	TFQFPN32	Onit		
In accord	ance with IEC 60747-17						
		Method a, type test,					
		tm = 10 s	1500	1500	V <sub>PEAK</sub>		
V <sub>PR</sub>	Input-to-output test voltage	partial discharge < 5 pC					
VPR		Method b, 100% production test,					
		tm = 1 s	1758	1758	V <sub>PEAK</sub>		
		partial discharge < 5 pC					
V <sub>IOTM</sub>	Transient overvoltage	Type test; t <sub>ini</sub> = 60 s	3537	4245	V <sub>PEAK</sub>		
V <sub>IOSM</sub>	Maximum surge insulation voltage	Type test	3537	4245	V <sub>PEAK</sub>		
R <sub>IO</sub>	Insulation resistance	Type test V <sub>IO</sub> = 500 V, T <sub>STG</sub> = 60 s	>10 <sup>9</sup>	>10 <sup>9</sup>	Ω		
UL1577							
V <sub>ISO</sub>	Insulation withstand voltage	1 min. type test	2000/2830	2500/3536	V <sub>RMS</sub> /V <sub>PEAK</sub>		
V <sub>ISO</sub> test	Insulation withstand test	1 s 100% production	2500/3537	3000/4245	V <sub>RMS</sub> /V <sub>PEAK</sub>		
Common Mode Transient Immunity							
dV <sub>ISO</sub> /dt	CMTI	Type test at V <sub>CM</sub> = 500 V	±25	±25	V/ns		

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### Table 13. Safety limits

Symbol	Parameter	Test conditions		Unit
Input saf	ety, Logic side			
T <sub>SI</sub>	Safety temperature of Logic side	-	150	°C
P <sub>SI</sub>	Safety power of Logic side <sup>(1)</sup>	$V_{DD} \le 6.0 \text{ V}, V_{LOGIC(x)} \le 6.0 \text{ V}, I_{LOGIC(x)} \le 10 \text{ mA}, T_J \le T_{SI}$	0.9	W
Output safety, Process side				
T <sub>SO</sub>	Safety temperature of Process side	-	150	°C
P <sub>SO</sub>	Safety power of Process side <sup>(1)</sup>	$V_{CC} \le 36 \text{ V, } I_{OUT(x)} \le 1.5 \text{ A, } T_J \le T_{SO}$	5	W

<sup>1.</sup> Respecting the above limits prevents potential damage to the isolation barrier upon failure on logic or process side circuitry. The user should apply these values to protect the IC and ensure the safety of the embedded isolation barrier. LOGIC(x) stands for any pin on the logic side; OUT(x) stands for any of the 8 output pins on the process side.

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## 6 Functional description

#### 6.1 Parallel interface

The integrated smart parallel interface offers three interfacing signals easily managed by a micro-controller. The  $\overline{\text{LOAD}}$  signal enables the input buffer storing the value of the channel inputs. The SYNC signal copies the input buffer value into the transmission buffer and manages the synchronization between low voltage side and the channel outputs on the isolated side.

The OUT\_EN signal enables the channel outputs. An internal refresh signal updates the configuration of the channel outputs with a  $f_{refresh}$  frequency. This signal can be disabled forcing low the  $\overline{SYNC}$  input when  $\overline{LOAD}$  is high.  $\overline{SYNC}$  and  $\overline{LOAD}$  pins can be in direct control mode (DCM) or synchronous mode (SCM).

#### 6.1.1 Input signals (IN1 to IN8)

Inputs from IN1 to IN8 are the <u>driving signals</u> of the corresponding OUT1 to OUT8 outputs. Data are directly <u>loaded</u> on related <u>outputs</u> if <u>SYNC</u> and <u>LOAD</u> inputs are low (DCM operation) or stored into input buffer when <u>LOAD</u> is low, and <u>SYNC</u> is high.

#### 6.1.2 Load input data (LOAD)

The input is active low; it stores the data from IN1 to IN8 into the input buffer

#### 6.1.3 Output synchronization (SYNC)

The input is active low; it enables the integrated transmission buffer loading input buffer data and manages the transmission between the two isolated sides of the device.

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#### 6.1.4 Watchdog

The IC is composed by two chips (Logic Stage and Process Stage) supplied by two independent and galvanic isolated sources ( $V_{DD}/GND_{DD}$  and  $V_{CC}/GND_{CC}$  pins, respectively). The IC provides a watchdog function in order to guarantee a safe condition for the Process Stage when  $V_{DD}$  (or  $GND_{DD}$ ) supply voltage is missing. If the Logic Stage does not update the output status within  $t_{WD}$ , all the outputs of the Process Stage are disabled until a new update request is received. The Logic Stage chip periodically sends a refresh signal to the Process Stage chip. The refresh signal is also considered a valid update signal to reset the timeout counter on the Process Stage, so the isolated side watchdog does not protect the system from a failure of the host controller (e.g., MCU freezing).

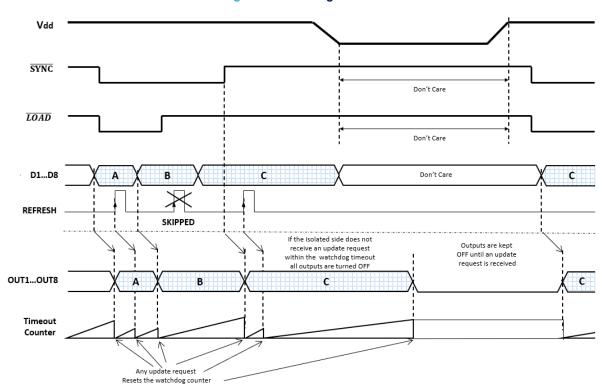
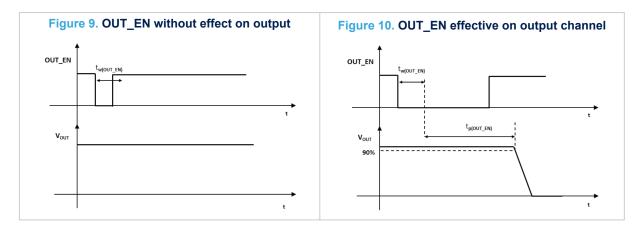


Figure 8. Watchdog behavior

#### 6.1.5 Output enable (OUT\_EN)

This pin provides a fast way to disable all the outputs simultaneously. When the OUT\_EN pin is driven low for at least  $t_{W(OUT\_EN)}$ , all eight outputs are disabled. This timing execution is compatible with an external reset push from the operator, safety requirements, and permits, in a PLC system, a micro-controller polling for obtain all internal information during a reset procedure.



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### 6.2 Direct Control Mode (DCM)

When SYNC and LOAD inputs are driven by the same signal, the device operates in direct control mode (DCM). In DCM the SYNC / LOAD signal operates as an active low input enable:

- · When the signal is high, the current output configuration is kept regardless the input values
- · When the signal is low, each channel input directly drives the respective output

This operation mode can also be set shorting both signals to the digital ground; in this case the channel outputs are always directly driven by the inputs except when OUT\_EN is low (outputs disabled).

 SYNC / LOAD
 OUT\_EN
 Device behavior

 Don't care
 Low<sup>(1)</sup>
 The outputs are disabled (turned off)

 High
 High
 The outputs are left unchanged

 Low
 High
 The channel inputs drive the outputs

Table 14. Interface signal operation in DCM

1. The outputs are turned off on OUT\_EN falling edge and they are kept disabled as long as it is low

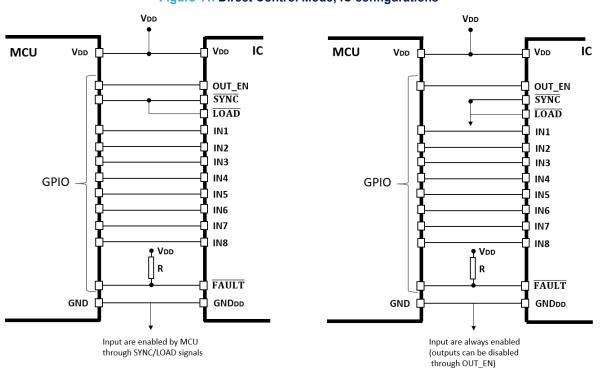


Figure 11. Direct Control Mode, IC configurations

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5

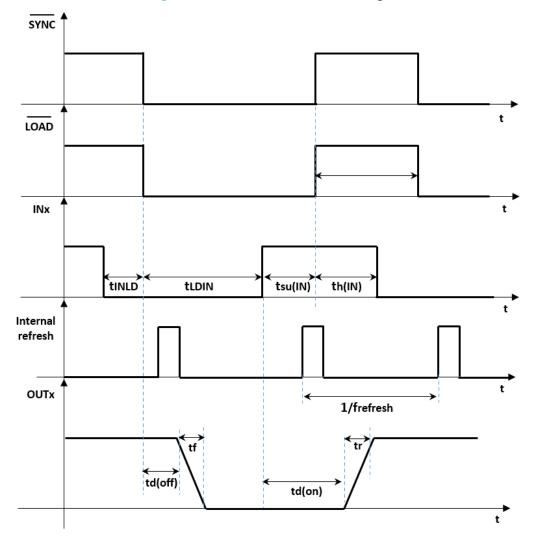


Figure 12. Direct Control Mode, time diagram

### 6.3 Synchronous control mode (SCM)

When  $\overline{\text{SYNC}}$  and  $\overline{\text{LOAD}}$  inputs are independently driven, the device can operate in synchronous control mode (SCM). The SCM is used to reduce the jittering of the outputs and to drive all outputs of different devices at the same time. In SCM the  $\overline{\text{LOAD}}$  signal is forced low to update the input buffer while the  $\overline{\text{SYNC}}$  signal is high. The  $\overline{\text{LOAD}}$  signal is raised and the  $\overline{\text{SYNC}}$  one is forced low for at least  $t_{\text{SYNC}(SCM)}$ . During this period, the internal refresh is disabled and any pending transmission between the low voltage and the isolated side is completed. When the  $\overline{\text{SYNC}}$  signal is raised the channel output configuration is changed according to the one stored in the input. If the  $t_{\text{SYNC}(SCM)}$  limit is met, the maximum jitter of the channel outputs is  $t_{\text{jitter}(SCM)}$ . If more devices share the same  $\overline{\text{SYNC}}$  signal, all device outputs change simultaneously with a maximum jitter related to maximum delay and maximum jitter for single device.

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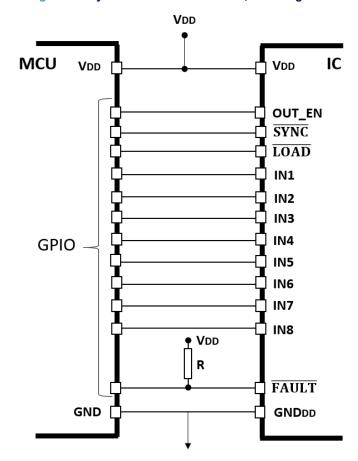


Table 1	5. In	terface s	signal	l opera	tion in	synch	ronous	mode

LOAD	SYNC	OUT_EN	Device behavior
Don't care	Don't care	Low <sup>(1)</sup>	The outputs are disabled (turned off)
High	High	High	The outputs are left unchanged
Low	High	High	The input buffer is enabled, the outputs are left unchanged
High	Low	High	The internal refresh signal is disabled, the transmission buffer is updated and the outputs are left unchanged
Low	Low	High	Should be avoided (DCM operation only)

1. The outputs are turned off on OUT\_EN falling edge and they are kept disabled as long as it is low.

Figure 13. Synchronous control mode, IC configuration



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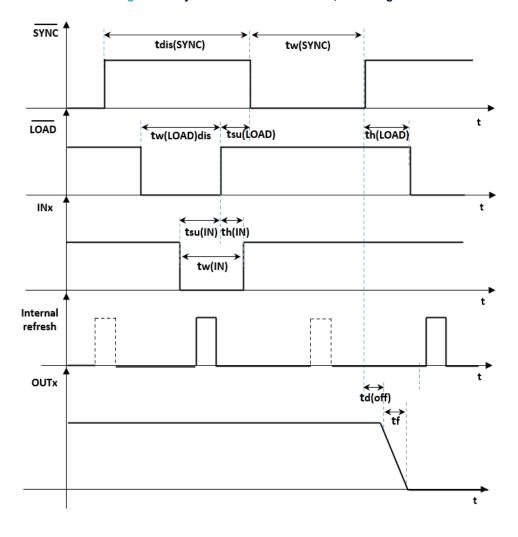
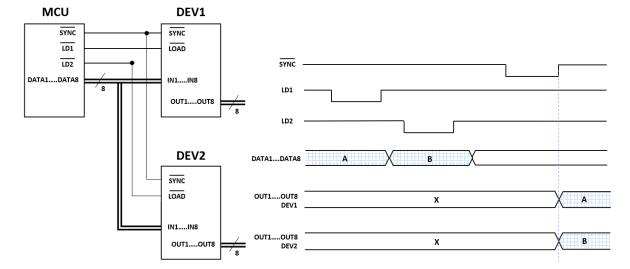


Figure 14. Synchronous Control Mode, time diagram





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#### 6.3.1 OUT\_EN behavior in Synchronous Control Mode

In SCM the OUT\_EN signal acts as a reset for the internal data register driving the output switches. When the OUT\_EN pin is driven low for at least  $t_{w(OUT\_EN)}$  (see Figure 16), all the eight outputs are disabled. OUTx remains low even if OUT\_EN is raised with INx already high: a new transition of LOAD and SYNC is required (see Figure 14).

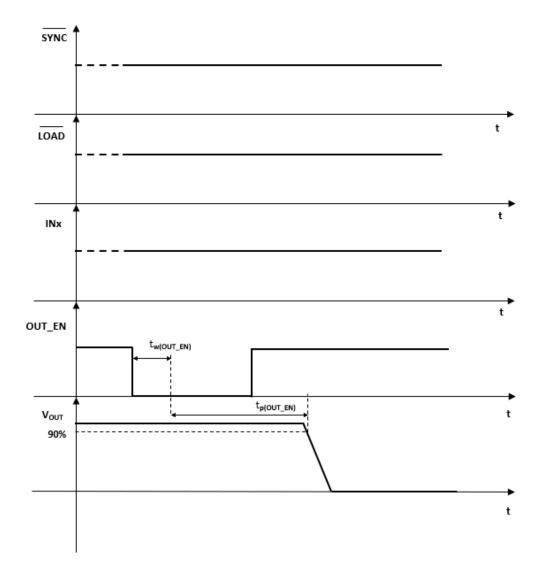


Figure 16. OUT\_EN behavior in Synchronous Control Mode, time diagram

#### 6.4 FAULT indication

The FAULT pin is an active low open drain output indicating fault conditions. This pin is activated when at least one of the following conditions occurs:

- Junction over-temperature (T<sub>JX</sub> >T<sub>JSD</sub>) of one or more channels of the Process Stage or case shut-down protection (T<sub>C</sub> >T<sub>CSD</sub>) is active
- Internal communication error.

The communication error is intended as an internal data corruption event in the data transfer through isolation. In case of communication error, the outputs are initially kept in the previous status and then reset (turned off) at the first communication error during data transfer of the refresh signal

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### 6.4.1 Junction overtemperature

The thermal status of the <u>device</u> is updated during <u>each</u> transmission sequence between the two isolated stages. In SCM operation, when  $\overline{\text{LOAD}}$  signal is high and  $\overline{\text{SYNC}}$  one is low, the communication between the two stages is disabled. In this case the thermal status of the device cannot be updated, and the  $\overline{\text{FAULT}}$  indication could be different to the actual status. In any case, the thermal protections of the channel outputs in the Process Stage are always operative.

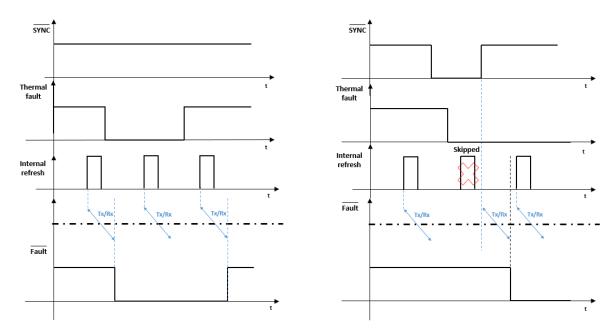


Figure 17. Thermal status update

#### 6.5 Truth table

Table 16. Truth table

x = maintain the previous condition.

Condition	Input IN <sub>x</sub>	OUT <sub>x</sub>	FAULT	
Normal operation	Н	ON	H (not active)	
Normal operation	L	OFF	TT (HOL active)	
Thermal Junction (T <sub>JX</sub> > T <sub>JSD</sub> )	Н	OFF	L (active)	
mermal surretion (TJX > TJSD)	L	OFF	H (not active)	
Thermal Case T <sub>C</sub> > T <sub>CSD</sub>	See Figure 24		H (not active) <sup>(1)</sup>	
V <sub>CC</sub> UVLO FAULT	L	OFF	X	
VCC OVEO I AGEI	Н	OIT	^	
V <sub>DD</sub> UVLO (Watchdog)	X	OFF	H (not active)	
Internal communication error	X	X	L (active)	

Usually, the thermal case is consequence of thermal junction event latching the FAULT pin low until the thermal junction event resets. If the thermal case is triggered without any thermal junction event (for example in case of very high ambient temperature) then the FAULT pin is not activated

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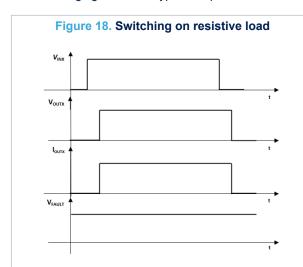


## 7 Power section

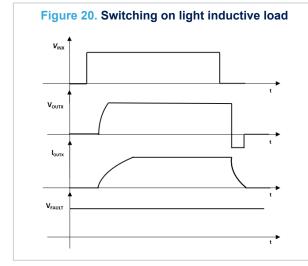
### 7.1 Current limitation

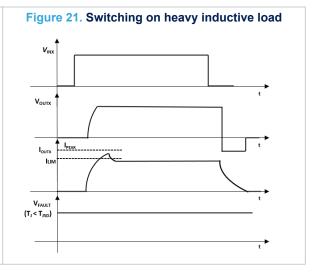
The current limitation process is activated when the current sense connected on the output stage measures a current value higher than a fixed threshold. When this condition is verified, the gate voltage is modulated to avoid output current increasing over the limitation value.

The following figures show typical output current waveforms with different load conditions.



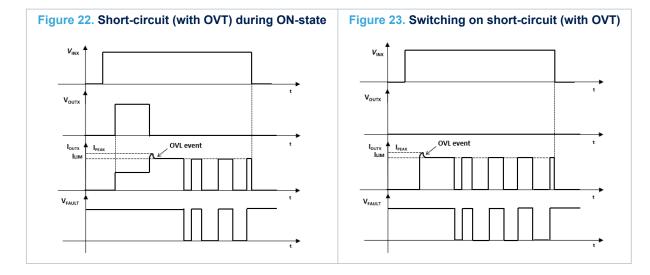
Vout Vout Vout (T, < T, SO)





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### 7.2 Thermal protection

The device is protected against overheating due to overload conditions. During driving period, if the output is overloaded, the device suffers two different thermal stresses, the first one related to the junction, and the second related to the case.

The two faults have different trigger thresholds: the junction protection threshold  $(T_{JSD})$  is higher than that of the case protection  $(T_{CSD})$ . Generally, the first protection that is activated in thermal stress conditions is the junction thermal shutdown. The output is turned off when the temperature is higher than the related threshold and turned back on when it falls below the reset threshold  $(T_{JR})$ . This behavior continues while the fault on the output is present.

If the thermal protection is active and the temperature of the package increases over the fixed case protection threshold, the case protection is activated, and the output is switched off and back on when the junction temperature of each channel in fault and case temperature are below the respective reset thresholds.

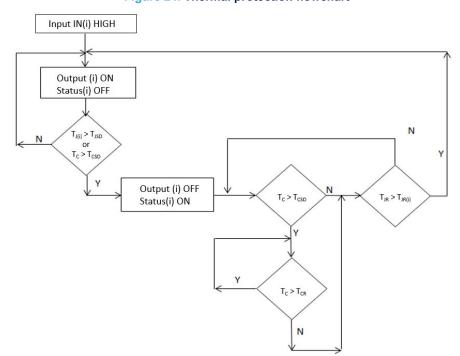


Figure 24. Thermal protection flowchart

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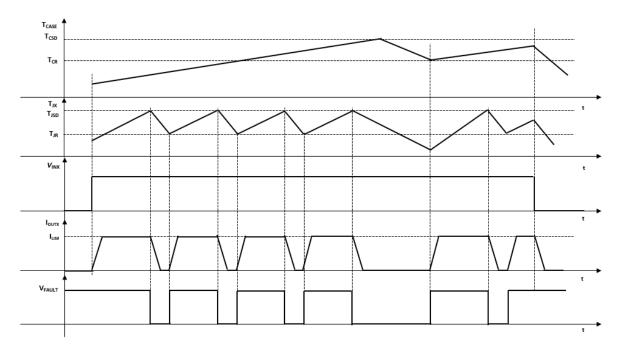
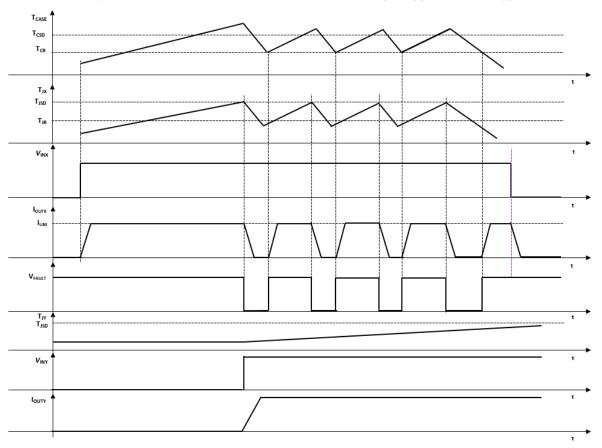


Figure 25. Thermal protection and fault behavior ( $T_{\text{JSD}}$  triggered before  $T_{\text{CSD}}$ )





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## 8 Reverse polarity protection

Reverse polarity protection can be implemented on the board using two different solutions (or both, which is recommended):

- 1. Placing a resistor (R<sub>GND</sub>) between IC GND pin and load GND
- 2. Placing a diode in parallel to a resistor between IC GND pin and load GND

If option 1 is selected, the minimum resistance value must be selected according to the following equation:

$$R_{GND} \ge \frac{V_{CC}}{I_{GND_{CC}}} \tag{1}$$

where  $I_{GNDCC}$  is the DC reverse ground pin current and can be found in Table 2.

The power dissipated by R<sub>GND</sub> during reverse polarity is:

$$P_D = \frac{\left(V_{CC}\right)^2}{R_{GND}} \tag{2}$$

If option 2 is selected, the diode has to be chosen by taking into account  $V_{RRM} > |V_{CC}|$  and its power dissipation capability:

$$P_D \ge I_S \times V_F \tag{3}$$

Note:

In normal operation (no reverse polarity), there is a voltage drop ( $\Delta V$ ) between GND of the device and GND of the system. Using option 1,  $\Delta V$  = Rgnd \* Icc. Using option 2,  $\Delta V$  = VF@(IF).

HVdd +Vcc

Outputi

GNDdd GNDcc

RGND
Diode

Load

Figure 27. Reverse polarity protection

Note: Input(i) is intended as any input pin on logic side.

This schematic can be used with any type of load.

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## 9 Reverse polarity on VDD

The reverse polarity on  $V_{DD}$  can be implemented on the board by placing a diode between the  $GND_{DD}$  pin and GND digital ground.

The diode must be chosen by taking into account  $V_{RRM} > |V_{DD}|$  and its power dissipation capability:

$$P_D \ge I_{DD} \times V_F \tag{4}$$

Note:

In normal operation (no reverse polarity), due to the diode, there is a voltage drop ( $\Delta V = VF@(Idd)$ ) between  $GND_{DD}$  of the device and digital ground of the system. In order to guarantee proper triggering of the input signal,  $\Delta V(max.)$  must result lower than  $V_{IH(MIN)}$ .

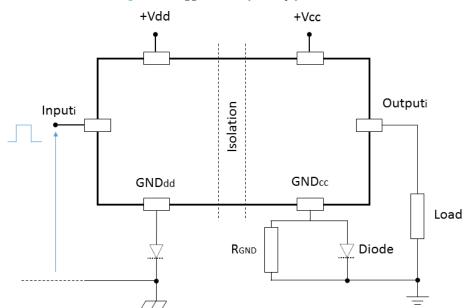


Figure 28. V<sub>DD</sub> reverse polarity protection

Note: Input(i) is intended as any input pin on logic side.

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## 10 Demagnetization energy

Figure 29. Single pulse demagnetization energy vs. load current (Typical values at T<sub>AMB</sub> = 125 °C)

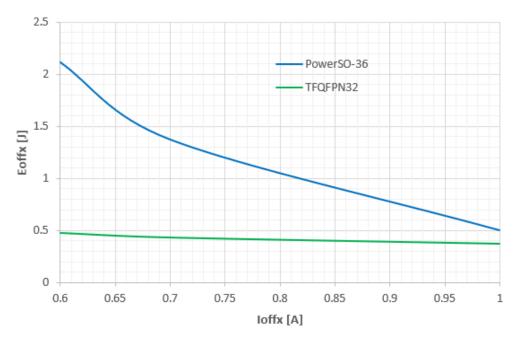


Figure 29 shows the single pulse (not repetitive) demagnetization capability per channel, all channels switched simultaneously

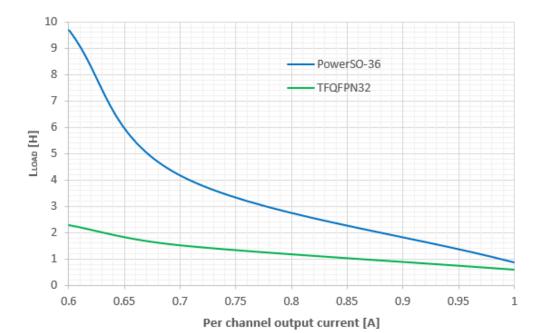


Figure 30. Single pulse inductive load capability vs. load current (T<sub>AMB</sub> = 125 °C)

Figure 30 shows the single pulse (not repetitive) inductive load capability per channel, all channels switched simultaneously

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## 11 Conventions

## 11.1 Supply voltage and power output conventions

Icc IDD **IFAULT** +V<sub>DD</sub> +Vcc **FAULT** lınx INX<sup>(1)</sup> ILOAD Io∪TX <u> LOAD</u>  $OUTX^{(1)}$  $V_{DD}$ Vcc Isync VFAULT SYNC VINX IOUT\_EN VLOAD Voutx OUT\_EN  $\mathsf{GND}_\mathsf{cc}$ Vsync GND<sub>DD</sub> Vout\_en (1): X = 1,...,8

Figure 31. Supply voltage and power output conventions

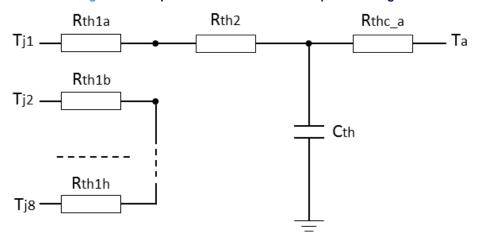
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# 12 Thermal information

## 12.1 Thermal impedance

Figure 32. Simplified thermal model of the process stage



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# 13 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

## 13.1 PowerSO-36 package information

DETAIL B

DETAIL A e3

DETAIL B

DETAIL A

DETAIL B

DET

Figure 33. PowerSO-36 package outline

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Table 17. PowerSO-36 package mechanical data

Div	mm				
Dim.	Min.	Тур.	Max.		
Α			3.6		
a1	0.10		0.30		
a2			3.30		
b	0.22		0.38		
С	0.23		0.32		
D <sup>(1)</sup>	15.80		16.00		
D1	9.40		9.80		
Е	13.90		14.50		
E1 <sup>(1)</sup>	10.90		11.10		
E2			2.90		
E3	5.80		6.20		
е		0.65			
e3		11.05			
G	0		0.10		
Н	15.50		15.90		
h			1.10		
L	0.80		1.10		
N			10°		
S	0°		8°		

 <sup>&</sup>quot;D" and "E1" do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm (0.006"). Critical dimensions are "a3", "E" and "G"

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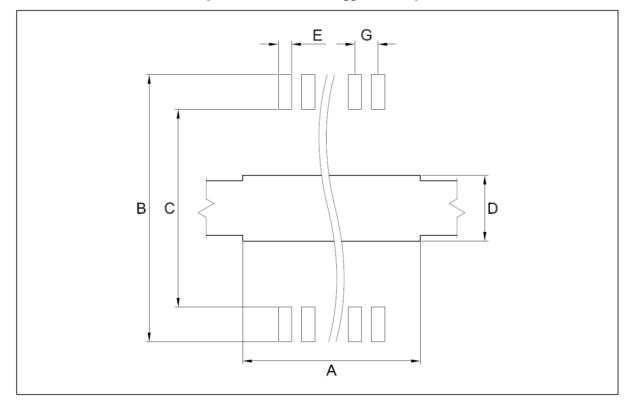


Figure 34. PowerSO-36 suggested footprint

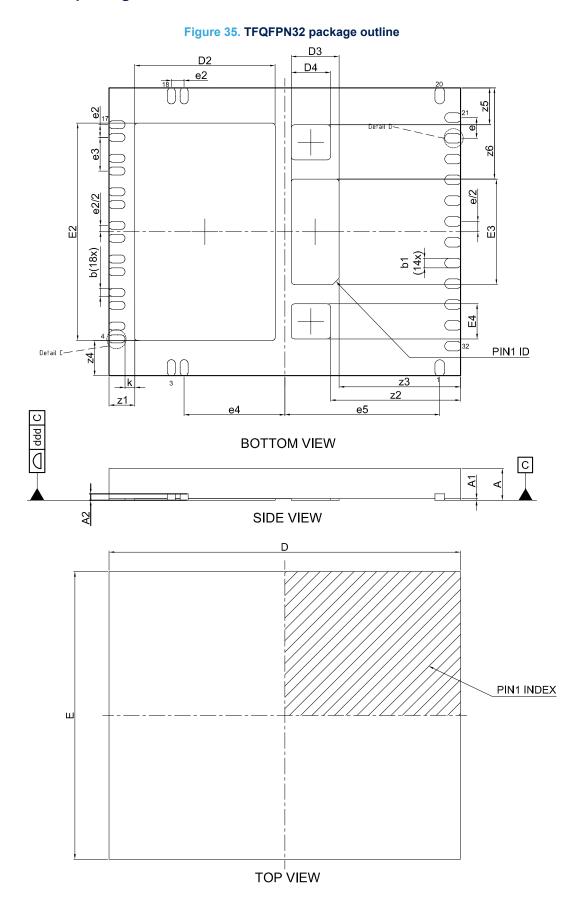
Table 18. PowerSO-36 footprint data

Dim	mm
А	9.5
В	14.7-15.0
С	12.5-12.7
D	6.3
E	0.42
G	0.65

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## 13.2



**TFQFPN32** package information

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Figure 36. TFQFPN32 package detail outline

Section A—A not in scale

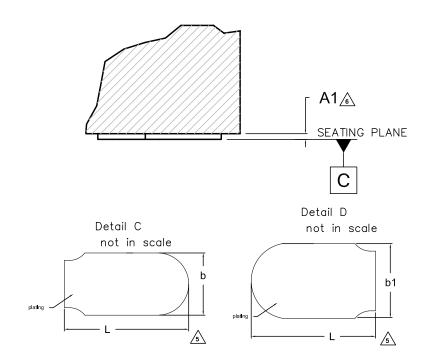
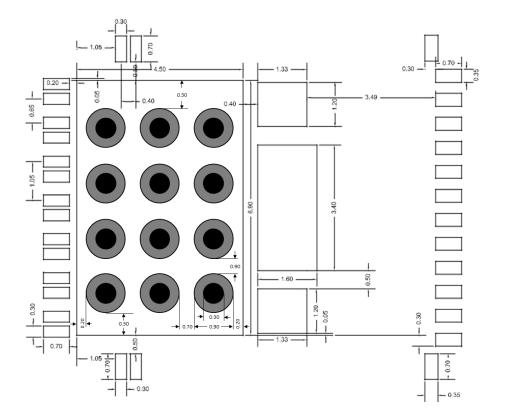


Figure 37. TFQFPN32 suggested footprint (measured in mm)



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Table 19. TFQFPN32 package mechanical data

Dim.	mm				
Dim.	Min.	Тур.	Max.		
А	0.95	1.00	1.05		
A1	0	-	0.05		
A2	-	0.20 REF	-		
b <sup>(1)</sup>	0.20	0.25	0.30		
b1 <sup>(1)</sup>	0.25	0.30	0.35		
D	10.90	11.0	11.10		
E <sup>(1)</sup>	8.90	9.00	9.10		
D2	4.30	4.40	4.50		
E2	6.70	6.80	6.90		
D3	1.40	1.50	1.60		
E3	3.20	3.30	3.40		
D4	1.13	1.23	1.33		
E4	1.00	1.10	1.20		
е	-	0.65	-		
e2	-	0.40	-		
e3	-	1.05	-		
e4	-	3.15	-		
e5	-	4.85	-		
k	0	0.30	-		
z1	-	0.80	-		
z2	-	4.07	-		
z3	-	3.80	-		
z4	-	1.10	-		
z5	-	1.15	-		
z6	-	2.85	-		
L <sup>(1)</sup>	0.45	0.50	0.55		

<sup>1.</sup> Dimensions "b" and "L" are measured on terminal plating surface.

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Table 20. Tolerance of form and position

Symbol	Tolerance of form and position	Definition	Notes
Aaa	0.15	The bilateral profile tolerance that controls the position of the plastic body sides. The centers of the profile zones are defined by the basic dimensions D and E.	-
Bbb	0.10	The tolerance that controls the position of the entire terminal pattern with respect to datums A and B. The center of the tolerance zone for each terminal is defined by the basic dimension "e" as related to datum's A and B.	-
Ccc	0.10	The tolerance located parallel to the seating plane in which the top surface of the package must be located.	-
ddd	0.08	The tolerance that controls the position of the terminals to each other. The centers of the profile zones are defined by basic dimension "e".	This tolerance is normally compounded with tolerance zone defined by bbb.
eee	0.08	The unilateral tolerance located above the seating plane where in the bottom surface of all terminals must be located.	This tolerance is commonly known as the "coplanarity" of the package terminals.
fff	0.10	The tolerance that controls the position of the exposed metal heat feature. The center of the tolerance zone will be datum's defined by the centerlines of the package body.	-
REF	-	-	No tolerance for A2

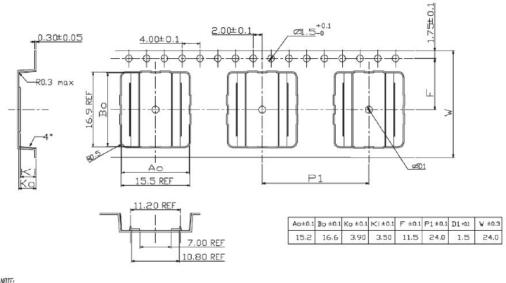
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## 14 Packing information

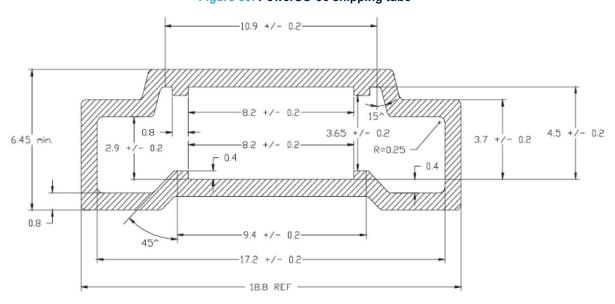
#### 14.1 PowerSO-36 packing information

Figure 38. PowerSO-36 carrier tape



D) Cumulative tolerance of 10 sprocket holes: 0.2nm 2) Camber: Inn/100nm max

Figure 39. PowerSO-36 shipping tube



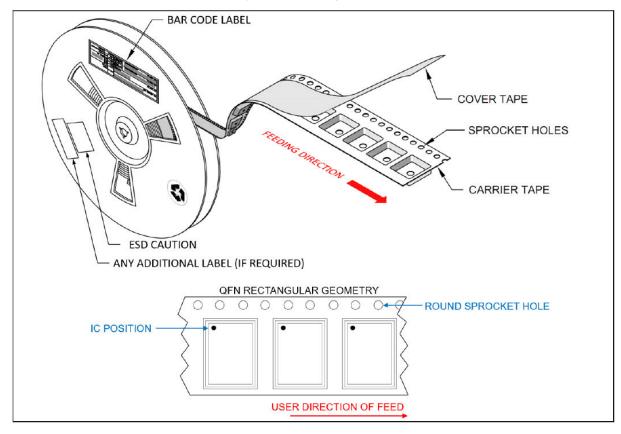
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#### 14.2 TFQFPN32 packing information

Packing Concept - Tape and Reel 13" in Dry Packing Humidity Desiccant Indicator Card Bag **Bulk Label** Plastic Reel Circular sprocket holes Protective opposite the label side of reel band Cover tape Inner Box Carrier tape **Enlongated** Carrier tape

Figure 40. Tape and reel packing method concept





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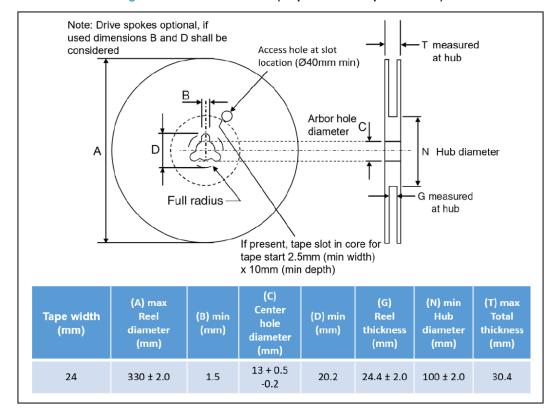
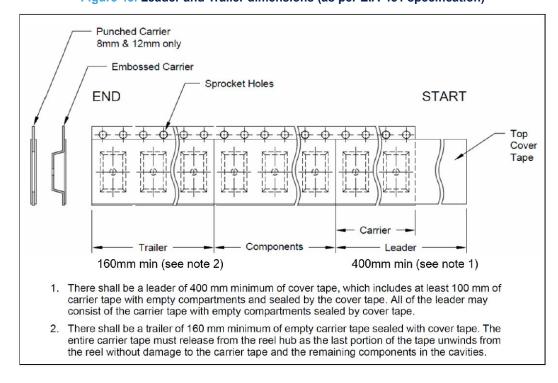


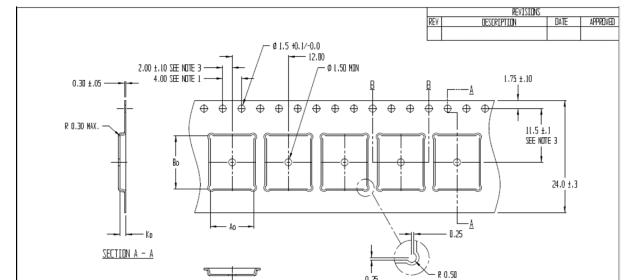
Figure 42. Reel dimensions (as per EIA-481 specification)

Figure 43. Leader and Trailer dimensions (as per EIA-481 specification)



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Ao = 9.40 Bo = 11.40 Ko = 1.30

SECTION B - B

0.25

Figure 44. TFQFPN32 carrier tape

NOTES:
1. 10 SPROCKET HOLE PITCH CLIMILATIVE TOLERANCE ±0.2
2. CAMBER IN COMPLIANCE WITH EIA 481
3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT PODGET HOLE

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# 15 Ordering information

Table 21. Ordering information

Part number	Package	Packaging
ISO808	PowerSO-36	Tube
ISO808-1	PowerSO-36	Tube
ISO808TR	PowerSO-36	Tape and reel
ISO808TR-1	PowerSO-36	Tape and reel
ISO808QTR	TFQFPN32	Tape and reel
ISO808QTR-1	TFQFPN32	Tape and reel

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## **Revision history**

Table 22. Document revision history

Date	Revision	Changes
21-Dec-2022	1	Initial release.
12- Sep-2023	2	Throughout the document added reference to TFQFPN32 package: changed Section Cover image; updated table in Section Product status link / summary; updated Section Features with ISO808Q/ISO808Q-1; updated first row in Description; added Figure 3; updated Table 1; updated Table 2; updated Table 3; updated Table 6, Table 11 and Table 12; deleted Table 14 in Section 6.1; added Section 6.3.1 and Section 6.5; updated Figure 18, Figure 19, Figure 20, Figure 21, Figure 22, Figure 23, Figure 25, Figure 26, Figure 29; added Figure 30; added Section 13.2, Section 14.2; updated Table 21.

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